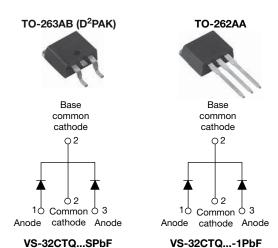


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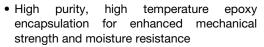
High Performance Schottky Rectifier, 2 x 15 A



PRODUCT SUMMARY					
TO-263AB (D ² PAK), TO-262AA					
2 x 15 A					
25 V, 30 V					
0.40 V					
7 mA at 125 °C					
175 °C					
Common cathode					
7.5 mJ					

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- · High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-32CTQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS	MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform	30	Α					
V _{RRM}		25, 30	V					
I _{FSM}	t _p = 5 μs sine	900	Α					
V _F	15 A _{pk} , T _J = 125 °C	0.40	V					
T _J	Range	-55 to +150	°C					

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-32CTQ025SPbF VS-32CTQ025-1PbF	VS-32CTQ030SPbF VS-32CTQ030-1PbF	UNITS		
Maximum DC reverse voltage	V_R	25	30	V		
Maximum working peak reverse voltage	V_{RWM}	25	30	V		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS VALUE				
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 115 °C	C, rectangular waveform	30			
Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load	900	Α		
surge current See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	250			
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1.20 \text{A}, L = 11$.10 mH	13	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero Frequency limited by T_J maxim		3	Α		



VS-32CTQ...SPbF, VS-32CTQ...-1PbF Series

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		15 A	T _{.1} = 25 °C	0.49		
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	30 A	1j=25 C	0.58	V	
	VFM (1)	15 A	T 105 °C	0.40	V	
		30 A	T _J = 125 °C	0.53		
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	1.75	mA	
See fig. 2		T _J = 125 °C		97	IIIA	
Threshold voltage	V _{F(TO)}	T T mayimum		0.233	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum		9.09	mΩ	
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal range	ge 100 kHz to 1 MHz), 25 °C	1300	pF	
Typical series inductance per leg	L _S	Measured lead to lead 5 m	nm from package body	8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	

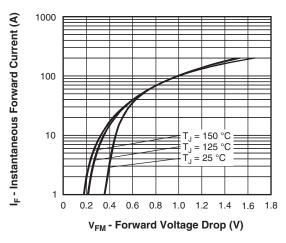
Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	•	T _J , T _{Stg}		-55 to +150	°C	
Maximum thermal resistance, junction to case per leg Typical thermal resistance, case to heatsink		R _{thJC}	DC operation See fig. 4	3.25	°C/W	
		R _{thCS}	Mounting surface, smooth and greased	0.50	G/ VV	
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
Manuskinaskausus	minimum			6 (5)	kgf · cm	
Mounting torque	maximum			12 (10)	(lbf \cdot in)	
			Occasion In P ² PAIX	32CT0	Q025S	
Marking device			Case style D ² PAK		Q030S	
			Constitute TO 000	32CTQ025-1		
			Case style TO-262		32CTQ030-1	

1000

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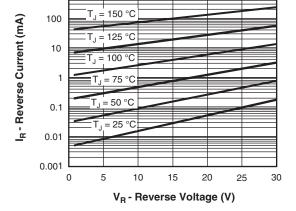


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

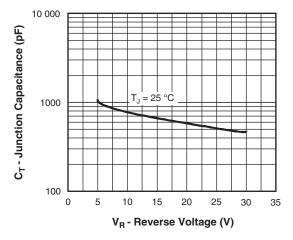


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

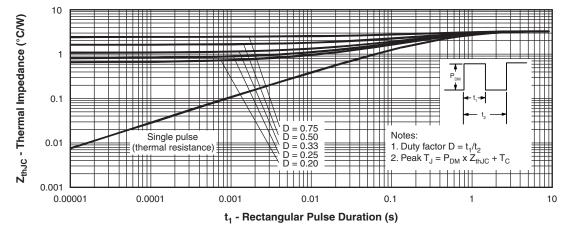


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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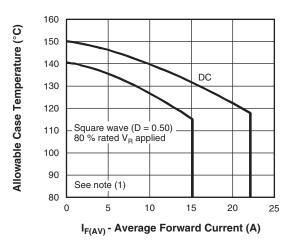


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

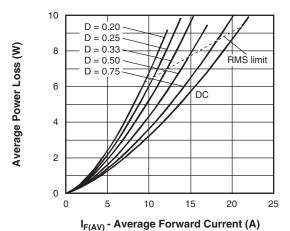


Fig. 6 - Forward Power Loss Characteristics

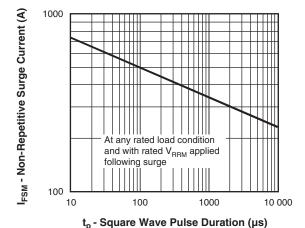


Fig. 7 - Maximum Non-Repetitive Surge Current

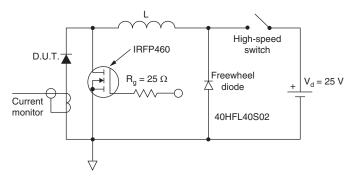


Fig. 8 - Unclamped Inductive Test Circuit

Note

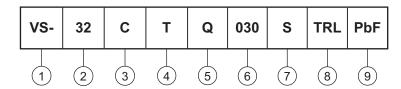
 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = 80 \text{ \% rated } V_R \\ \end{array}$

VS-32CTQ...SPbF, VS-32CTQ...-1PbF Series

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Current rating (30 A)

3 - Circuit configuration: C = common cathode

4 - T = TO-220

5 - Schottky "Q" series

6 - Voltage ratings 025 = 25 V 030 = 30 V

7 - • S = D²PAK

• -1 = TO-262

8 - • None = tube (50 pieces)

• TRL = tape and reel (left oriented - for D²PAK only)

• TRR = tape and reel (right oriented - for D²PAK only)

9 - PbF = lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-32CTQ025SPBF	50	1000	Antistatic plastic tubes			
VS-32CTQ025STRRPBF	800	800	13" diameter plastic tape and reel			
VS-32CTQ025STRLPBF	800	800	13" diameter plastic tape and reel			
VS-32CTQ025-1PBF	50	1000	Antistatic plastic tubes			
VS-32CTQ030SPBF	50	1000	Antistatic plastic tubes			
VS-32CTQ030STRRPBF	800	800	13" diameter plastic tape and reel			
VS-32CTQ030STRLPBF	800	800	13" diameter plastic tape and reel			
VS-32CTQ030-1PBF	50	1000	Antistatic plastic tubes			

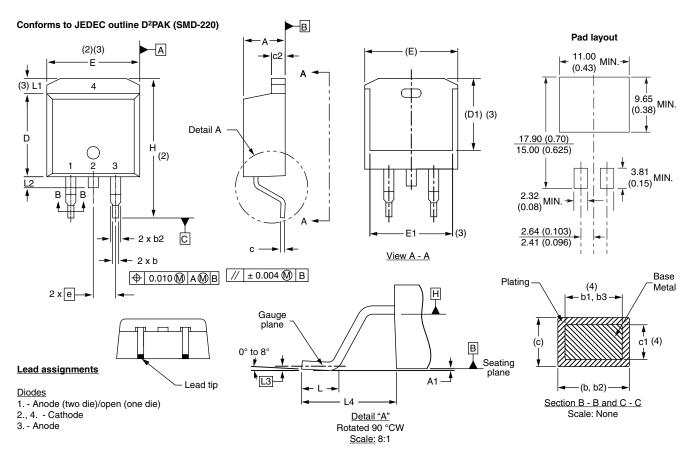
LINKS TO RELATED DOCUMENTS					
Dimensions	TO-263AB (D ² PAK)	www.vishay.com/doc?95046			
Dimensions	TO-262AA	www.vishay.com/doc?95419			
Part marking information		www.vishay.com/doc?95008			
Packaging information		www.vishay.com/doc?95032			



Vishay High Power Products

D²PAK, **TO-262**

DIMENSIONS FOR D²PAK in millimeters and inches



CVMDOL	MILLIM	IETERS	INC	HES	NOTEC
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

(7) Outline conforms to JEDEC outline TO-263AB

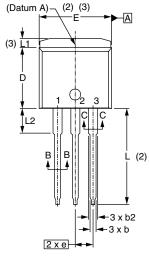
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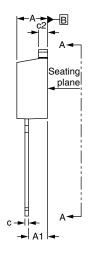
D²PAK, TO-262

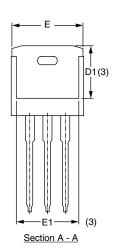


DIMENSIONS FOR TO-262 in millimeters and inches

Modified JEDEC outline TO-262 (Datum A) (2) (3)







⊕ 0.010**⋒**|A**⋒**|B

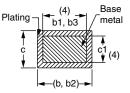
Lead assignments



Diodes

1. - Anode (two die)/open (one die) 2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

OVMDOL	MILLIM	ETERS	INC	INCHES		
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
Е	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54	BSC	0.100) BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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